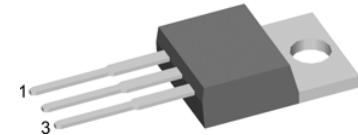
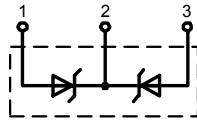


Schottky

High Performance Schottky Diode
Low Loss and Soft Recovery
Common Cathode

Part number (*Marking on product*)

DSB 30 C 45PB

**Features / Advantages:**

- Very low V_f
- Extremely low switching losses
- Low I_{rm}-values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package:

- TO-220AB
- Industry standard outline
 - Epoxy meets UL 94V-0
 - RoHS compliant

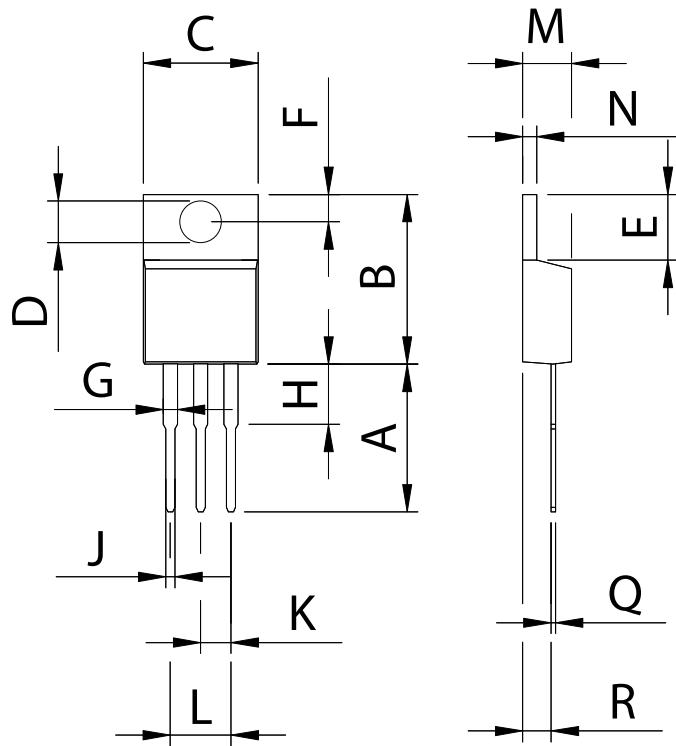
Ratings					
Symbol	Definition	Conditions	min.	typ.	max.
V _{RRM}	max. repetitive reverse voltage	T _{vJ} = 25 °C			45
I _R	reverse current	V _R = 45 V T _{vJ} = 25 °C V _R = 45 V T _{vJ} = 100 °C		10 50	mA
V _F	forward voltage	I _F = 15 A T _{vJ} = 25 °C I _F = 30 A I _F = 15 A T _{vJ} = 125 °C I _F = 30 A		0.59 0.83 0.55 0.80	V
I _{FAV}	average forward current	rectangular, d = 0.5 T _c = 125 °C			15
V _{F0} r _F	threshold voltage slope resistance } for power loss calculation only	T _{vJ} = 150 °C		0.31 15.5	V mΩ
R _{thJC}	thermal resistance junction to case			1.75	K/W
T _{vJ}	virtual junction temperature		-55	150	°C
P _{tot}	total power dissipation	T _c = 25 °C		70	W
I _{FSM}	max. forward surge current	t _p = 10 ms (50 Hz), sine T _{vJ} = 45 °C		160	A
C _J	junction capacitance	V _R = V; f = 1 MHz T _{vJ} = 25 °C			pF
E _{AS}	non-repetitive avalanche energy	I _{AS} = A; L = 100 μH T _{vJ} = 25 °C		tbd	mJ
I _{AR}	repetitive avalanche current	V _A = 1.5 · V _R typ.; f = 10 kHz		tbd	A

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
I_{RMS}	RMS current	per pin*			35	A
R_{thC}	thermal resistance case to heatsink			0.50		K/W
M_D	mounting torque		0.4		0.6	Nm
F_c	mounting force with clip		20		60	N
T_{stg}	storage temperature		-55		150	°C
Weight				2		g

* I_{RMS} is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

Outlines TO-220AB



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	12.70	13.97	0.500	0.550
B	14.73	16.00	0.580	0.630
C	9.91	10.66	0.390	0.420
D	3.54	4.08	0.139	0.161
E	5.85	6.85	0.230	0.270
F	2.54	3.18	0.100	0.125
G	1.15	1.65	0.045	0.065
H	2.79	5.84	0.110	0.230
J	0.64	1.01	0.025	0.040
K	2.54	BSC	0.100	BSC
M	4.32	4.82	0.170	0.190
N	1.14	1.39	0.045	0.055
Q	0.35	0.56	0.014	0.022
R	2.29	2.79	0.090	0.110